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Analysis of oxygen vacancy in Co-doped ZnO using the electron density distribution obtained using MEM

Ji Hun Park^{1†}, Yeong Ju Lee^{1,2†}, Jong-Seong Bae³, Bum-Su Kim¹, Yong Chan Cho⁴, Chikako Moriyoshi⁵, Yoshihiro Kuroiwa⁵, Seunghun Lee^{6,7*} and Se-Young Jeong^{1*}

Abstract

Oxygen vacancy (V_O) strongly affects the properties of oxides. In this study, we used X-ray diffraction (XRD) to study changes in the V_O concentration as a function of the Co-doping level of ZnO. Rietveld refinement yielded a different result from that determined via X-ray photoelectron spectroscopy (XPS), but additional maximum entropy method (MEM) analysis led it to compensate for the difference. V_O tended to gradually decrease with increased Co doping, and ferromagnetic behavior was not observed regardless of the Co-doping concentration. MEM analysis demonstrated that reliable information related to the defects in the ZnO-based system can be obtained using X-ray diffraction alone.

Keywords: ZnO; Rietveld refinement; Maximum entropy method; Oxygen vacancy; Co-doped ZnO

Background

Oxygen vacancy (V_O), one of the representative native defects in oxides, has received much attention because of the important role played thereby in determining the physical properties of materials [1-3]. Various tools have been used for the qualitative and quantitative analysis of V_O . These include photoluminescence [4], ultraviolet-visible (UV-vis) [5], Raman [5], and X-ray photoelectron spectroscopic (XPS) techniques [6]. Quantitative analyses of V_O have been successfully performed via Rutherford backscattering spectroscopy [7] or X-ray absorption spectroscopy using synchrotron radiation [8]. Additionally, X-ray diffraction (XRD) is a simple and useful tool for analysis of V_O because it reveals the crystal structure and the electron density distribution of periodic arrays of atoms [9].

Fitting of X-ray diffraction data using the Rietveld refinement has been attempted for the quantitative analyses of V_O in terms of oxygen site occupancy [10,11].

However, additional corrections and the use of neutron or synchrotron X-rays were required [11-13]. Electron density profiling using the maximum entropy method (MEM) is also a suitable tool for analysis of V_O because it uses the more precise Rietveld refinement that resolves summation-terminated errors and affords a better structural model [14,15]. Furthermore, MEM introduces negligible modeling errors via least-biased electronic reconstruction of X-ray diffraction patterns in real space [15].

We sought to confirm whether MEM analysis could be used for analysis of V_O . In this study, we applied such analysis to V_O that changed as a function of the Co-doping concentration in ZnO. Co-doped ZnO is a good candidate room-temperature magnetic semiconductor and has been intensively studied in terms of intrinsic ferromagnetism. However, the origin of such ferromagnetism remains controversial, and the presence thereof limits applications of the semiconductor. V_O was regarded, until recently, to explain the ferromagnetism and was reported to be affected by Co-doping concentration [8]. Herein, we analyzed the change in V_O as a function of Co-doping concentration and compared the results with XPS data. A method of analysis of V_O is proposed, using conventional XRD and MEM techniques.

* Correspondence: seunghun2@korea.ac.kr; syjeong@pusan.ac.kr

[†]Equal contributors

⁶The Institute of Basic Science, Korea University, Seoul 136-713, Republic of Korea

¹Department of Cogno-Mechatronics Engineering, Pusan National University, Miryang 627-706, South Korea

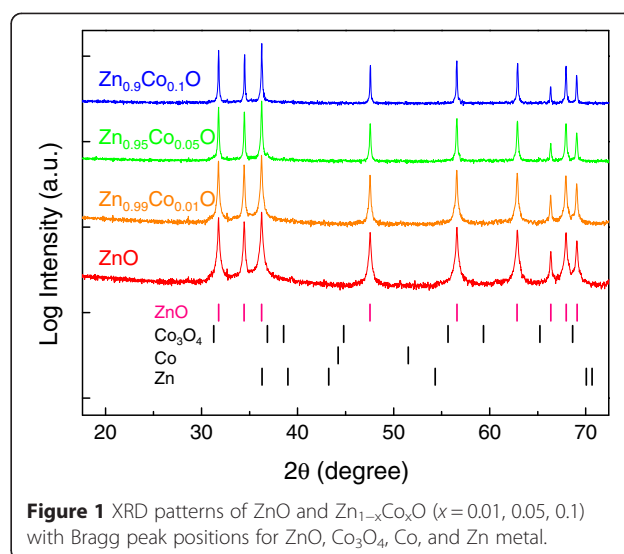
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Methods

ZnO and Co-doped ZnO ($\text{Zn}_{1-x}\text{Co}_x\text{O}$, $x = 0.01, 0.05, 0.1$) powder samples were fabricated by sol-gel methods [16,17]. Zinc acetate dihydrate (Sigma-Aldrich, St. Louis, MO, USA) and cobalt acetate tetrahydrate (Sigma-Aldrich, St. Louis, MO, USA), used as starting materials, were dissolved in 2-methoxyethanol (Sigma-Aldrich, St. Louis, MO, USA) and stabilized by monoethanolamine (Sigma-Aldrich, St. Louis, MO, USA). To exclude the possibility of external contamination, the dissolution and drying processes were performed under a pure argon gas (99.999% purity) atmosphere, and under vacuum, each for 10 h, respectively. The organic residuals in samples were completely removed via an intermediate heat treatment at 300°C and a subsequent final heat treatment at 800°C under vacuum for 10 h [16]. The samples used in this study were characterized using XRD, and we found a high degree of crystallinity, which was comparable to that of commercially available high-quality powder samples (ZnO; CAS 1314-13-2, Sigma-Aldrich, St. Louis, MO, USA). We also characterized the samples using synchrotron radiation, and we found high sample quality. A characterization study using synchrotron radiation will be submitted to a specialized journal soon. XRD (Empyrean Series 2, PANalytical) experiments were performed to analyze the crystal structures and electron density distributions of the powder samples. The Rietveld and MEM analyses were performed using a published technique [18]. The MEM calculation was performed using ENIGMA software [19] with $66 \times 66 \times 104$ pixels. The electron density distribution was reconstructed using the VESTA visualization program [20]. An X-ray photoelectron spectrometer (model: Theta Probe (Thermo Electron Co., Waltham, MA, USA), Korean Basic Science Institute, Busan Center) was used for atomic composition analysis. Magnetic-field-dependent magnetization was measured using a vibrating sample magnetometer (VSM) equipped with a physical property measurement system (PPMS; Model 6000, Quantum Design, San Diego, CA, USA).

Results and discussion

Figure 1 shows the XRD patterns of the ZnO and ZnCoO powder samples. The Bragg peaks correspond to the wurtzite ZnO structure and other possible secondary species [16,21]. The diffraction intensity of each sample is presented logarithmically to better observe the background levels. Figure 1 shows that the XRD patterns of all samples had pronounced diffraction peaks that corresponded to wurtzite ZnO, with no additional peaks corresponding to secondary phases (at least within the detection limits). This indicates that the Co^{2+} ions were well-substituted during doping into Zn sites, without creation of secondary species [16,22]. Doping



Co into ZnO tended to decrease the full-width at half-maximum (FWHM) values of XRD peaks. To quantitatively analyze this trend, the grain sizes of each powder sample were calculated using the Scherrer equation [23]. These sizes were estimated to be 93, 107, 115, and 143 nm for ZnO, $\text{Zn}_{0.99}\text{Co}_{0.01}\text{O}$, $\text{Zn}_{0.95}\text{Co}_{0.05}\text{O}$, and $\text{Zn}_{0.9}\text{Co}_{0.1}\text{O}$, respectively. Co doping thus improved the crystallinity of the samples, in proportional to the Co-doping concentration, in our experimental range [24]. The crystallinity of ZnO can be greatly affected by lattice strain [25] or native defects such as V_O [26-28] and interstitial zinc (Zn_i) [27,28]. The contribution of lattice strain (resulting from the Co-doping concentration) to differences in crystallinity was assumed to be negligible because all powder samples were post-annealed at both 300°C and 800°C [17,29], which would relieve any lattice strain. Co doping was thought to induce insignificant amounts of lattice strain that might result from a difference in ionic radii, because the ionic radius of Zn^{2+} (74 pm) is similar to that of Co^{2+} (72 pm) [30]. Consequently, the observed enhancement in the crystallinity of the samples was attributed to a decrease in the density of crystal defects caused by Co doping. A quantitative analysis of V_O and Zn_i was performed to explore this hypothesis; we refined the XRD patterns of the samples.

Figure 2 shows the Rietveld refinement results for the ZnO and ZnCoO samples performed using single-phase wurtzite ZnO. The reliability factors based on the Bragg intensity (R_I) and structure factor (R_F) were below 1.5% and 0.8%, respectively, for all samples (Table 1). The refinement results revealed that the lattice constants steadily increased with increasing Co-doping level. It is known that formation of Zn_i leads to an increase in lattice constants [31], while

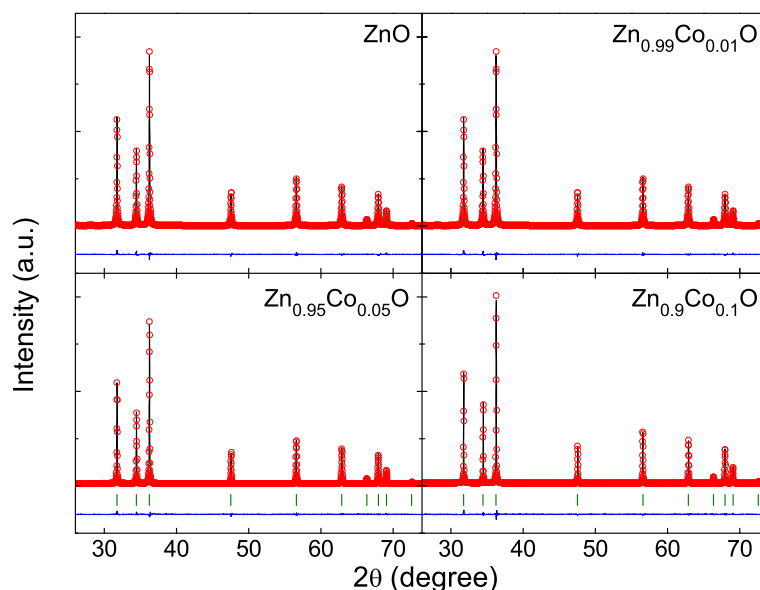


Figure 2 Powder XRD patterns and Rietveld refinement results. Powder XRD patterns (black lines) and Rietveld refinement results (red circles) of ZnO, Zn_{0.99}Co_{0.01}O, Zn_{0.95}Co_{0.05}O, and Zn_{0.9}Co_{0.1}O samples. The differences between the XRD patterns and Rietveld refinement results are indicated by the lower blue lines. The green bars provide the calculated Bragg peak positions.

formation of V_O induces a decrease in lattice constants [32]. The observed reduction of internal defects, and the increased lattice constants with increasing Co-doping level, indicated that the main defects embedded in the ZnO sample were V_O , and hence, their density decreased as the Co-doping concentration increased.

An additional Rietveld refinement of the oxygen occupancies in each finalized Rietveld refinement was performed to examine the validity of this concept. Table 1 also lists the change in the oxygen occupancy [$\Delta g_O = (g_O(\text{ZnO}) - g_O(\text{ZnCoO}))/g_O(\text{ZnO})$] for each sample, where g_O refers to oxygen site occupancy. The oxygen occupancy increased for Zn_{0.99}Co_{0.01}O (i.e., negative Δg_O was obtained) but decreased for Zn_{0.95}Co_{0.05}O and Zn_{0.9}Co_{0.1}O. Also, the oxygen vacancy was greater for

Zn_{0.95}Co_{0.05}O than for Zn_{0.9}Co_{0.1}O. MEM analysis was used to further examine this trend.

It was expected that the presence of V_O in ZnO and ZnCoO would induce changes in the electron density distributions of the oxygen atoms. Hence, the electron densities of the oxygen atoms as a function of Co-doping concentration were investigated via MEM/Rietveld analysis [18]. Figure 3a,b show electron density maps of the ZnO and Zn_{0.9}Co_{0.1}O samples in the (110) plane, respectively. The Zn sites of the ZnO sample and the Zn(Co) sites of the Zn_{0.9}Co_{0.1}O sample did not noticeably differ in electron density. This is because of the low-dopant concentration used, and because Zn and Co exhibited similar electron density distributions, as Zn²⁺ and Co²⁺ have similar total numbers of electrons [33,34]. However, the electron densities at the central O atoms of ZnO and Zn_{0.9}Co_{0.1}O were clearly different, thus, 20.65 and 21.91 e/Å³, respectively. This indicated that the oxygen sites in the wurtzite ZnO structure became increasingly occupied by oxygen atoms after Co doping. Thus, Co doping decreased the V_O content.

Figure 3c shows the electron density line profiles along the direction of the O-Zn bond. These profiles enable precise analysis of oxygen occupancy as a function of the Co content. The lines were normalized to the electron density at the Zn(Co) atomic position to allow comparison of V_O with Zn occupancy. The electron density at the O atomic position increased in the order

Table 1 Reliability factors of ZnO and ZnCoO samples

Sample	R_I (%)	R_F (%)	a (Å)	Δg_O (%)
ZnO	1.473	0.731	3.24989	-
Zn _{0.99} Co _{0.01} O	1.066	0.605	3.25084	-0.39
Zn _{0.95} Co _{0.05} O	0.942	0.509	3.25120	2.03
Zn _{0.9} Co _{0.1} O	0.776	0.414	3.25235	3.48

Reliability factors based on the Bragg intensity (R_I) and structure factor (R_F), lattice constants (a), and relative change in oxygen site occupancies (Δg_O) of ZnO and ZnCoO samples. g_O refers to the site occupancy at the oxygen atom in the Rietveld refinement.

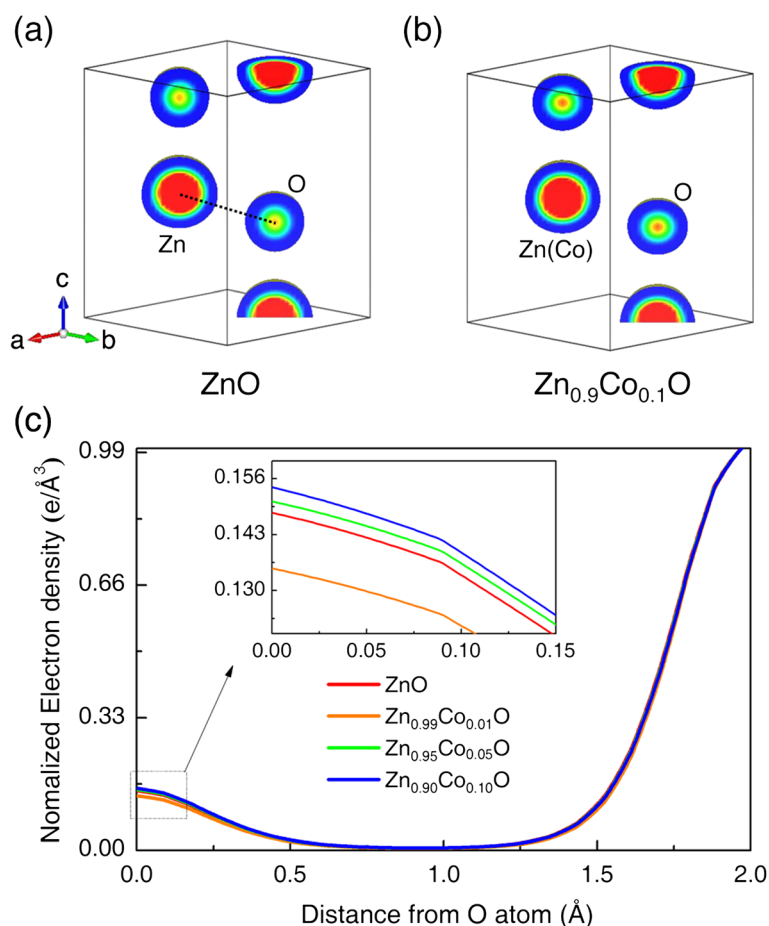


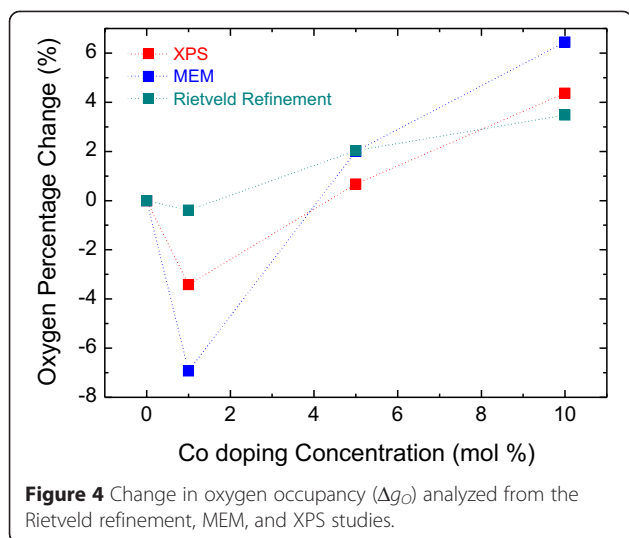
Figure 3 Electron density distribution and line profiles. Electron density distribution of (a) ZnO and (b) Zn_{0.9}Co_{0.1}O on the (110) plane obtained from Rietveld/MEM analyses. (c) Electron density line profiles of the ZnO and ZnCoO samples along the O-Zn(Co) bond (indicated by the dotted line in (a)). The inset is a magnification of the line profiles around the O atoms.

Zn_{0.99}Co_{0.01}O < ZnO < Zn_{0.95}Co_{0.05}O < Zn_{0.9}Co_{0.1}O, in agreement with the Rietveld refinement results. The sample with 1% Co doping exhibited significantly lower oxygen electron density, which did not agree with the Rietveld refinement data.

XPS was used to rationalize the conflicting V_O results. Figure 4 shows the percentage change in oxygen occupancy as a function of Co concentration as determined by the Rietveld refinement, MEM, and XPS techniques. The MEM data were calculated from the integrals of the electron density profiles of the Zn(Co) and O atom positions shown in Figure 3c and the ratio of the oxygen electron density area to the Zn(Co) electron density area. The change in oxygen occupancy revealed by XPS was obtained from the integrals of the areas of the Zn 2p, Co 2p, and the O 1s peaks. The calculation of change in oxygen occupancy was performed on the basis of a pure ZnO sample without Co dopant, as per the data of Table 1. The MEM and XPS results both showed that the sample with 1 mol% Co doping exhibited an abrupt

drop in oxygen content; the samples with more doping had increased oxygen contents, in agreement with both the Rietveld refinement and the MEM results. Consequently, the XPS profile results were in better agreement with the MEM results than with the data from the Rietveld refinement. This indicated that MEM analysis, via repeated error correction, provided more accurate structural information. These findings suggest that reliable defect analysis may be possible using easily accessed laboratory X-ray data.

The magnetic field dependences of magnetization (M-H curves) were measured for all samples (Figure 5a). Pure ZnO is diamagnetic, and Co-doped ZnO exhibits paramagnetic behavior because of the 3d electron of Co²⁺. We reconfirmed that the ZnCoO samples were not intrinsically ferromagnetic, regardless of Co concentration [6,16]. Figure 5b shows the magnetic susceptibilities, which are the slopes of the M-H curves; these increased nonlinearly with increased Co-doping level. With increasing Co concentration, not all Co spins behave



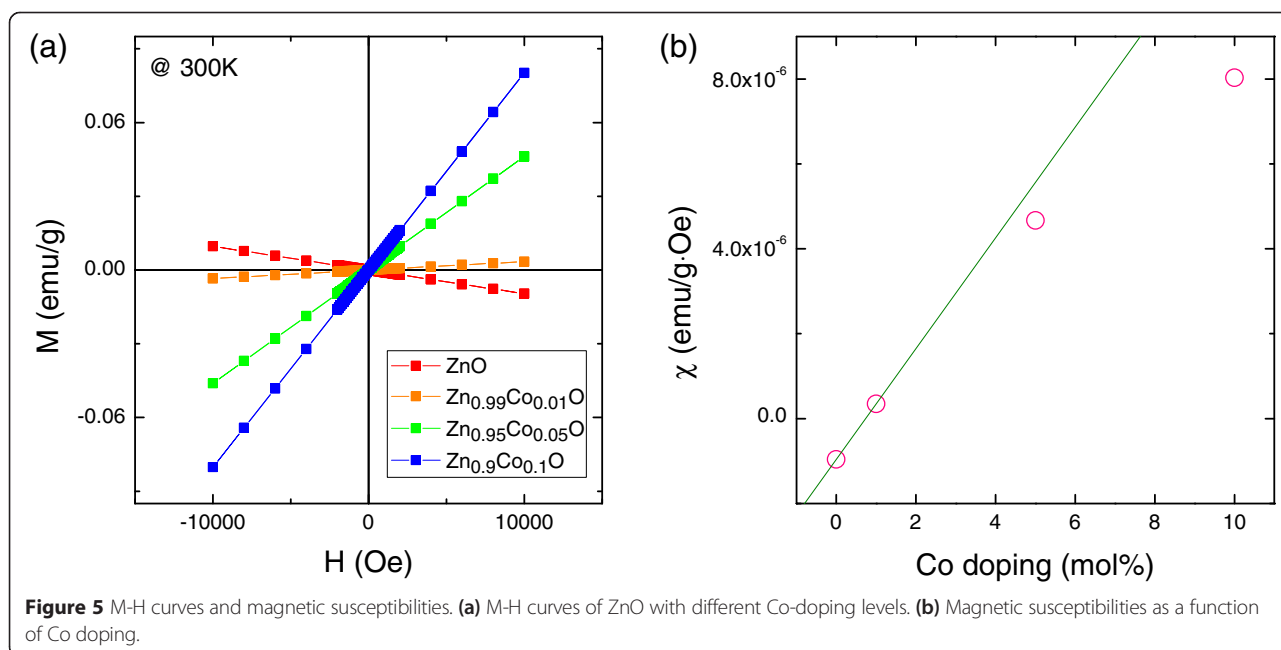
paramagnetically; some spins assume configurations differing in alignment. Considering the absence of secondary phases in the above structural analysis, we conjecture that increasing numbers of Co atoms assuming positions neighboring oxygen atoms created an antiferromagnetic configuration via superexchange interaction.

The observed trend, that creation of V_O was suppressed with increasing Co-doping level, is attributable to differences in the Zn-O and Co-O bond strengths; the O^{2-} ions in the wurtzite ZnO structure are tetrahedrally coordinated and thereby form four Zn-O bonds [35]. Doping of Co^{2+} ions into ZnO creates Co-O bonds, the diatomic

bond dissociation energy of which is higher than that of the Zn-O bond by 84 kJ/mol (Zn-O: 284 kJ/mol, Co-O: 368 kJ/mol) [36]. This indicates that the Co-O bonds created by Co doping enhanced the average bond strength between oxygen ions and neighboring cations, i.e., doping decreased the possibility of oxygen-cation bond dissociation during sample fabrication or post-treatment processing [36]. The experimental results indicate that V_O decreased at high-level Co doping (i.e., above 5 mol%). The supporting analyses suggest that Co doping can impede creation of V_O . However, the abrupt increase of V_O at 1 mol% of Co doping is not well-understood and warrants additional study.

Conclusions

The Rietveld refinement results of the X-ray diffraction patterns of the ZnCoO system indicated that increased Co doping of ZnO tended to decrease the V_O , but the V_O increased slightly upon 1 mol% of Co doping. The MEM results were in better agreement with the XPS data, which indicated that MEM analysis could be a reliable tool for the study of V_O . Additional research is needed to explain the anomalous behavior at 1 mol% of Co doping. More advanced X-ray electron density studies using synchrotron radiation would provide more precise and reliable data, but nevertheless, our present work shows that MEM is a reliable technique for the analysis of defects in materials characterized by XRD, which is a readily accessible tool in the material scientist laboratory. This approach will be of particular value in early-stage studies of oxide systems.



Competing interests

The authors declare that they have no competing interests.

Authors' contributions

JHP designed and planned the experiment. JHP and YJL carried out Rietveld refinement and MEM analysis. JSB contributed to experiments and analysis for XPS. BSK performed powder sample fabrication. YCC assisted with sample characterization and manuscript preparation. CM and YK contributed to MEM analysis. SL performed data analysis and guided this work. JHP, SL, and SYJ wrote the main manuscript with help from the co-authors. SYJ is responsible for project planning. All authors discussed the results and reviewed the manuscript. All authors read and approved the final manuscript.

Authors' information

JHP, BSK and YJL are graduate students of the Department of Cogno-Mechatronics Engineering, Pusan National University, Republic of Korea. JSB is a senior researcher of Korea Basic Science Institute (Busan Center), Republic of Korea. YCC is a research professor at the Crystal Bank Institute, Pusan National University, Republic of Korea. CM and YK are professors at the Department of Physical Science, Hiroshima University, Japan. SL, the corresponding author, is a research scholar at the Department of Materials Science and Engineering, University of Maryland. SYJ, the corresponding author, is a professor at the Department of Cogno-Mechatronics Engineering, Pusan National University, Republic of Korea.

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Author details

¹Department of Cogno-Mechatronics Engineering, Pusan National University, Miryang 627-706, South Korea. ²Department of Nanofusion Engineering, Pusan National University, Busan 609-735, South Korea. ³Busan Center, Korea Basic Science Institute, Busan 618-230, South Korea. ⁴Frontier in Extreme Physics, Korea Research Institute of Standards and Science, Daejeon 305-340, South Korea. ⁵Department of Physical Science, Hiroshima University, Higashi-Hiroshima 739-8526, Japan. ⁶The Institute of Basic Science, Korea University, Seoul 136-713, Republic of Korea. ⁷Current address: Department of Materials Science and Engineering, University of Maryland, College Park, MD 20742, USA.

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